

### Applications

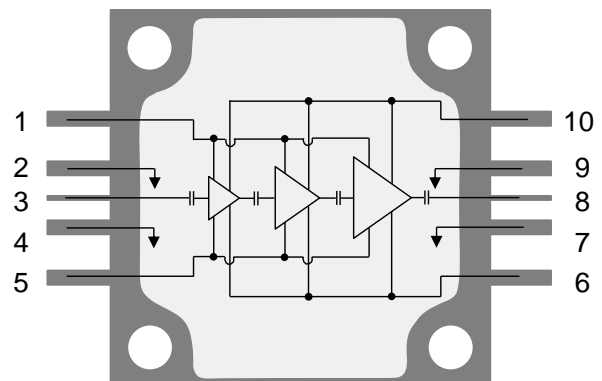
- Weather and Marine Radar



### Product Features

- Frequency Range: 9 – 10 GHz
- Pout: 42 dBm ( $P_{IN} = 15$  dBm)
- PAE: > 37 % ( $P_{IN} = 15$  dBm)
- Power Gain: 27 dB ( $P_{IN} = 15$  dBm)
- Bias:  $V_D = 28$  V,  $I_{DQ} = 365$  mA,  $V_G = -2.6$  V typical (Pulsed: PW = 100  $\mu$ s, DC = 10%)
- Package Dimensions: 15.2 x 15.2 x 3.5 mm
- Package base is pure Cu offering superior thermal management

### Functional Block Diagram



### General Description

TriQuint's TGA2624-CP is a packaged high-power X-Band amplifier fabricated on TriQuint's TQGaN25 0.25  $\mu$ m GaN on SiC process. Operating from 9 to 10 GHz, the TGA2624-CP achieves 42 dBm saturated output power, a power-added efficiency of > 37 %, and power gain of 27 dB.

The TGA2624-CP is packaged in a 10-lead 15x15 mm bolt-down package with a Cu base for superior thermal management. It can support a range of bias voltages and performs well under both pulsed and CW conditions. Both RF ports are internally DC blocked and matched to 50 ohms allowing for simple system integration.

The TGA2624-CP is ideally suited for both commercial and defense applications.

Lead free and RoHS compliant.

Evaluation Boards are available upon request.

### Pin Configuration

Pad No.	Symbol
1, 5	$V_G$
2, 4, 7, 9	GND
3	RF <sub>IN</sub>
6, 10	$V_D$
8	RF <sub>OUT</sub>

### Ordering Information

Part	ECCN	Description
TGA2624-CP	3A001.b.2.b	9 – 10 GHz, 16 W GaN Power Amplifier

### Absolute Maximum Ratings

Parameter	Value
Drain Voltage ( $V_D$ )	40 V
Gate Voltage Range ( $V_G$ )	-8 to 0 V
Drain Current ( $I_D$ )	3 A
Gate Current ( $I_G$ )	-6 to 14 <sup>(1)</sup> mA
Power Dissipation ( $P_{DISS}$ ), 85°C	53 W
Input Power, CW, 50 $\Omega$ , ( $P_{IN}$ )	21 dBm
Input Power, CW, VSWR 6:1, $V_D = 28$ V, 85 °C, ( $P_{IN}$ )	21 dBm
Channel Temperature ( $T_{CH}$ )	275 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

- (1) Max rating for  $I_G$  is at Channel Temperature ( $T_{CH}$ ) of 200 °C .

### Recommended Operating Conditions

Parameter	Value
Drain Voltage ( $V_D$ ): Pulsed	28 V
Drain Current ( $I_{DQ}$ )	365 mA
Drain Current Under RF Drive ( $I_{D\_DRIVE}$ )	See plots p. 6
Gate Voltage ( $V_G$ )	-2.6 V (Typ.)
Gate Current Under RF Drive ( $I_{G\_DRIVE}$ )	See plots p. 6
Temperature ( $T_{BASE}$ )	-40 to 85 °C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

### Electrical Specifications

Test conditions unless otherwise noted: 25 °C,  $V_D = 28$  V (PW = 100  $\mu$ s, DC = 10 %),  $I_{DQ} = 365$  mA,  $V_G = -2.6$  V typical.

Parameter	Min	Typical	Max	Units
Operational Frequency Range	9		10	GHz
Small Signal Gain		36.5		dB
Input Return Loss		> 10		dB
Output Return Loss		> 9		dB
Output Power (at $P_{IN} = 15$ dBm)		42		dBm
Power Added Efficiency (at $P_{IN} = 15$ dBm)		> 37		%
Power Gain (at $P_{IN} = 15$ dBm)		27		dB
Output Power Temperature Coefficient (25 °C to 85 °C only)	Pulsed CW	-0.003 -0.01		dBm/°C
Recommended Operating Voltage	25	28	32	V

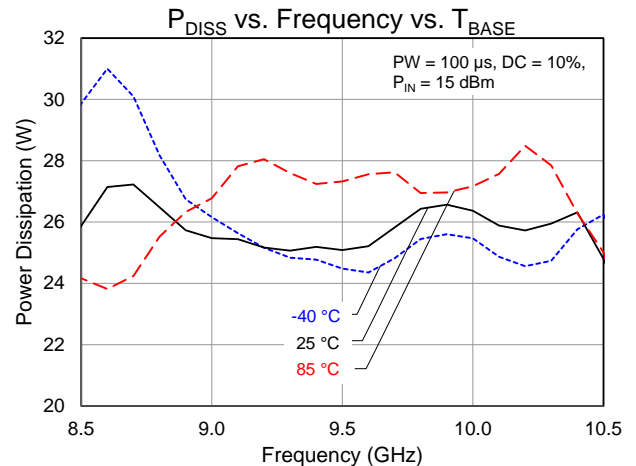
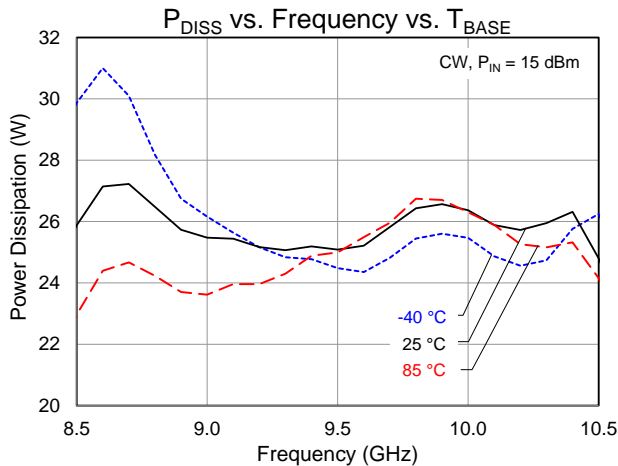
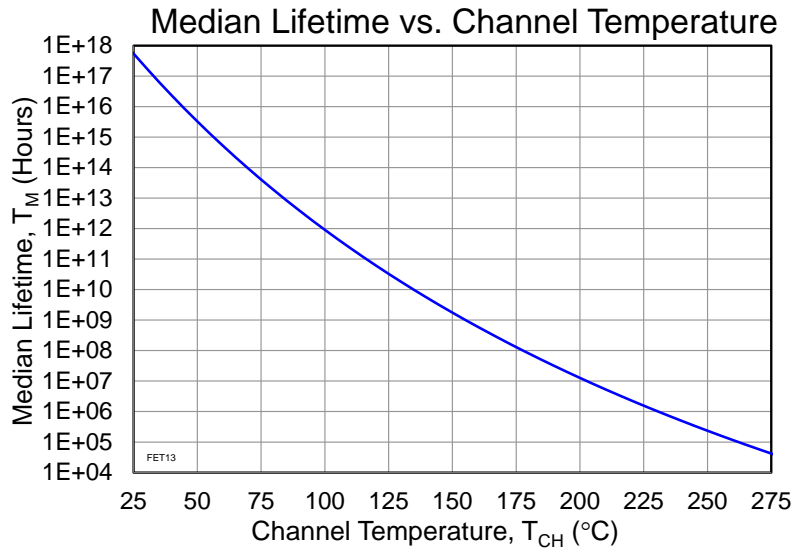
### Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	CW, $V_D = 28$ V, $I_{DQ} = 365$ mA,	3.4	$^{\circ}\text{C}/\text{W}$
Channel Temperature ( $T_{CH}$ ) (under RF drive)	$T_{BASE} = 85^{\circ}\text{C}$ , Freq = 9.5 GHz, $P_{IN} = 15$ dBm,	174	$^{\circ}\text{C}$
Median Lifetime ( $T_M$ )	$P_{OUT} = 42.2$ dBm $P_{DISS} = 26$ W, $I_{D\_Drive} = 1.49$ A	1.4E+8	Hrs
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$V_D = 28$ V, $I_{DQ} = 365$ mA,	2.24	$^{\circ}\text{C}/\text{W}$
Channel Temperature ( $T_{CH}$ ) (under RF drive)	(Pulsed: $PW = 100$ $\mu\text{s}$ , $DC = 10\%$ ),	147	$^{\circ}\text{C}$
Median Lifetime ( $T_M$ )	$T_{BASE} = 85^{\circ}\text{C}$ , Freq = 9.5 GHz, $P_{IN} = 15$ dBm,	2.5E+10	Hrs
	$P_{OUT} = 42.7$ dBm, $P_{DISS} = 27$ W, $I_{D\_Drive} = 1.64$ A		

Notes:

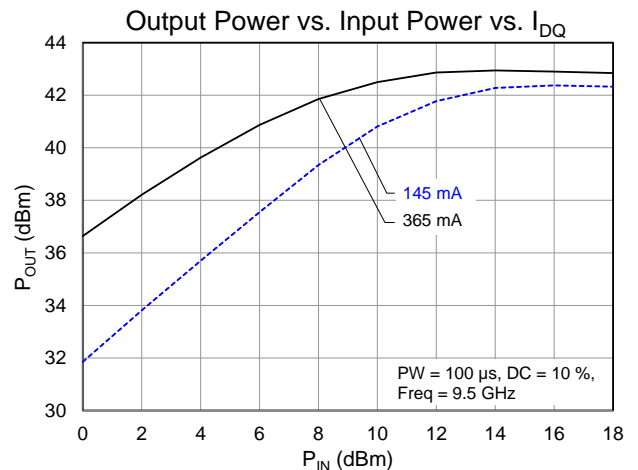
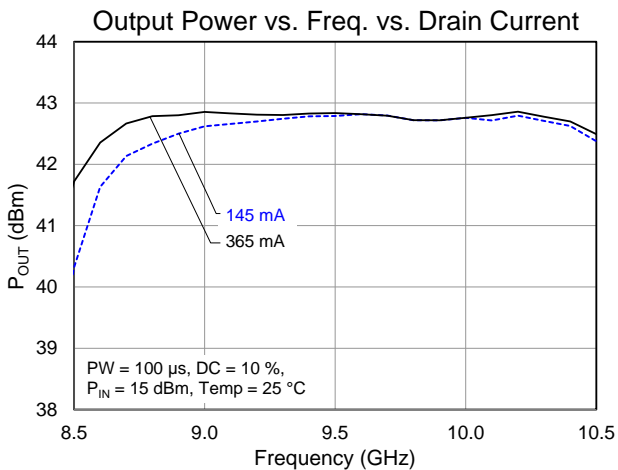
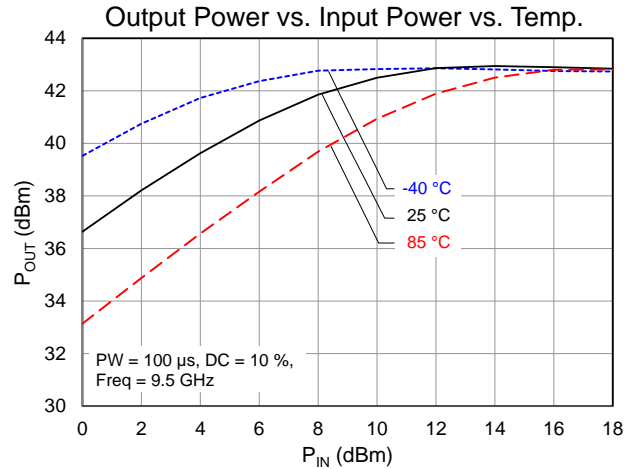
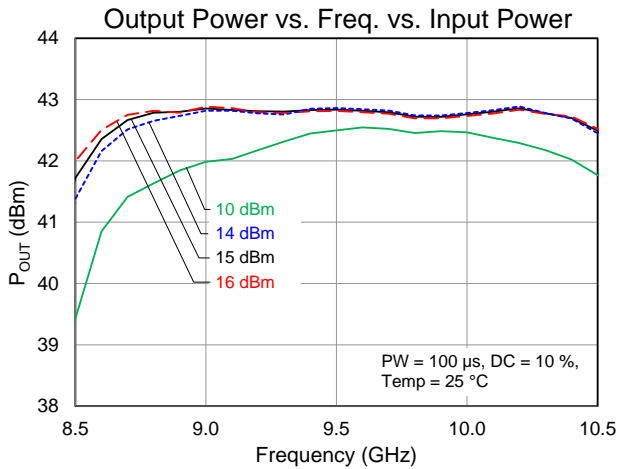
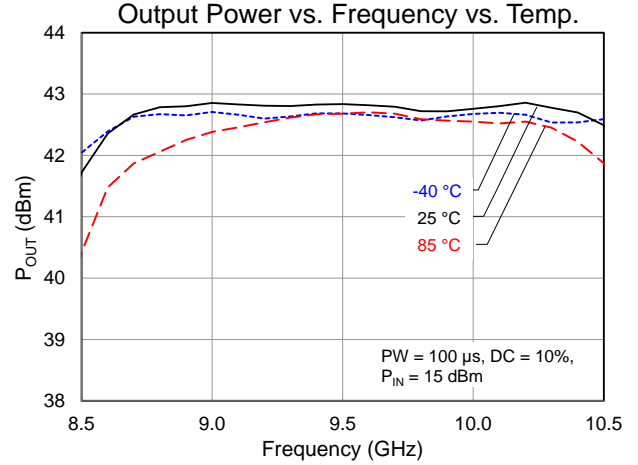
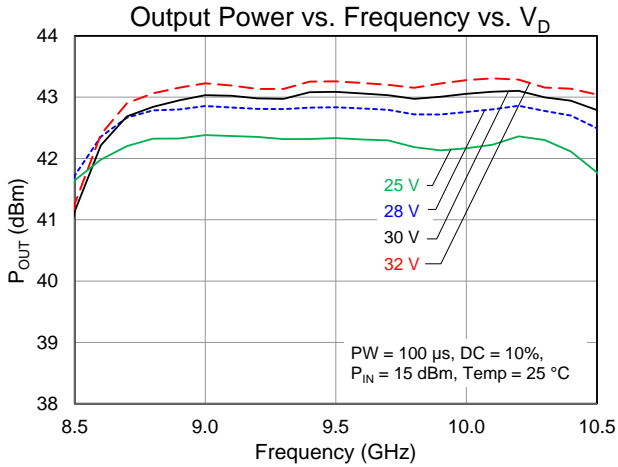
1. Thermal resistance measured to back of package.

Test Conditions:  $V_D = 40$  V; Failure Criteria = 10% reduction in  $I_{D\_MAX}$



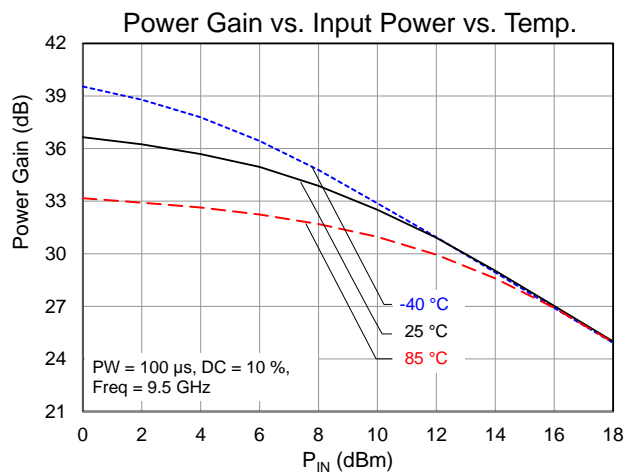
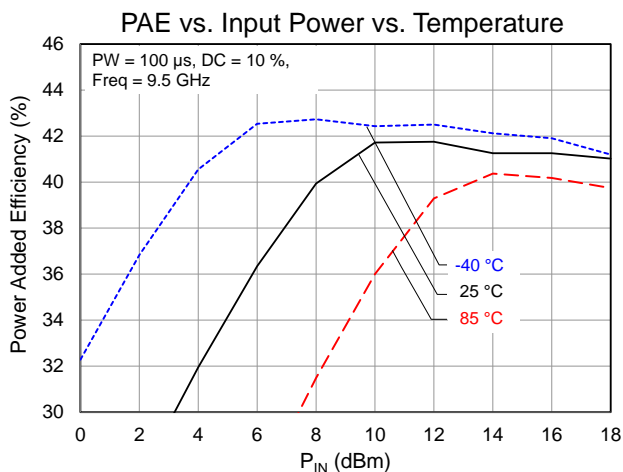
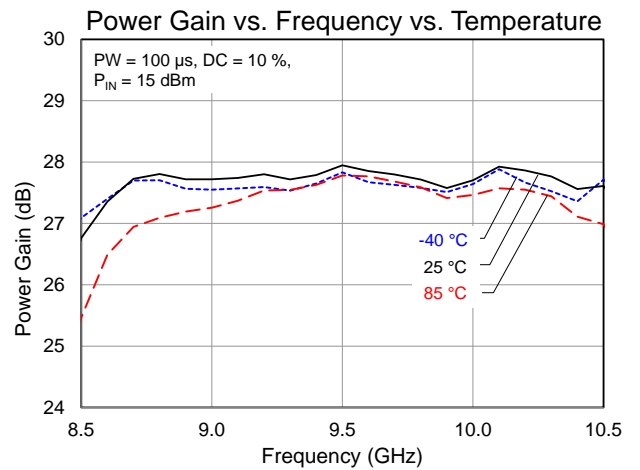
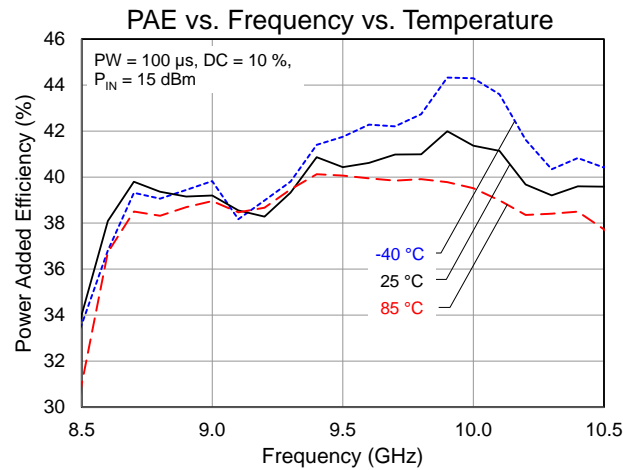
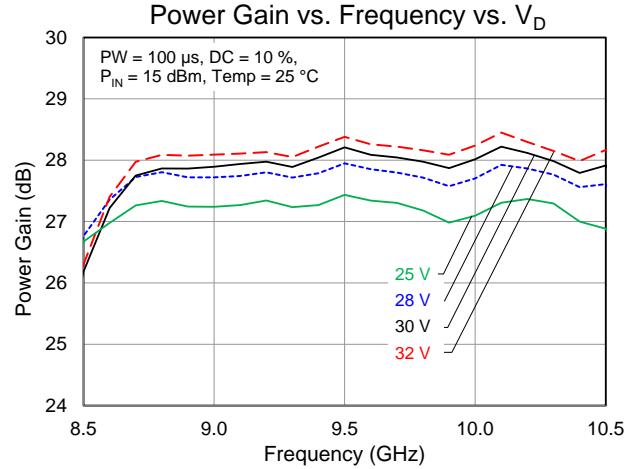
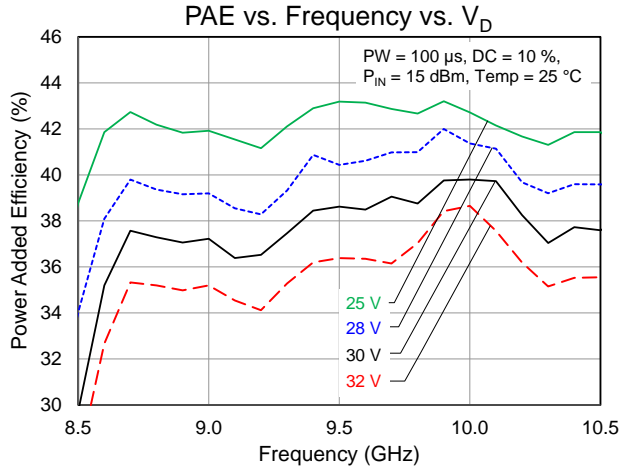
### Typical Performance: Large Signal

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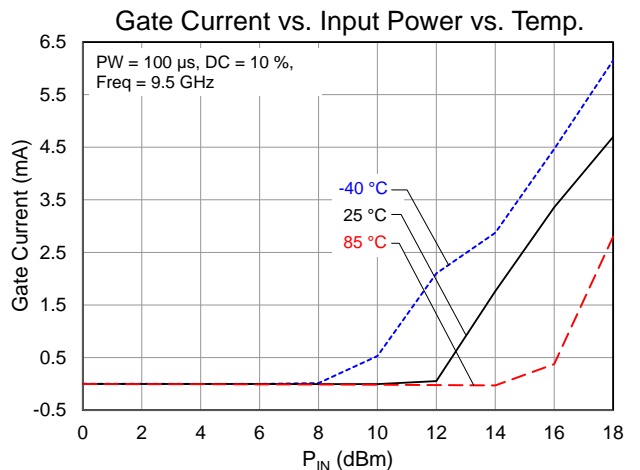
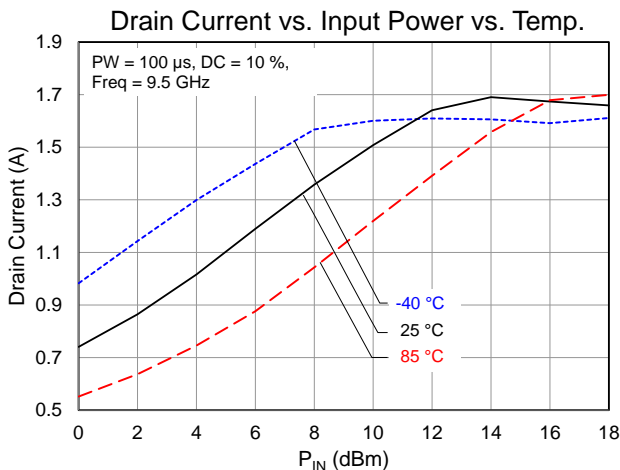
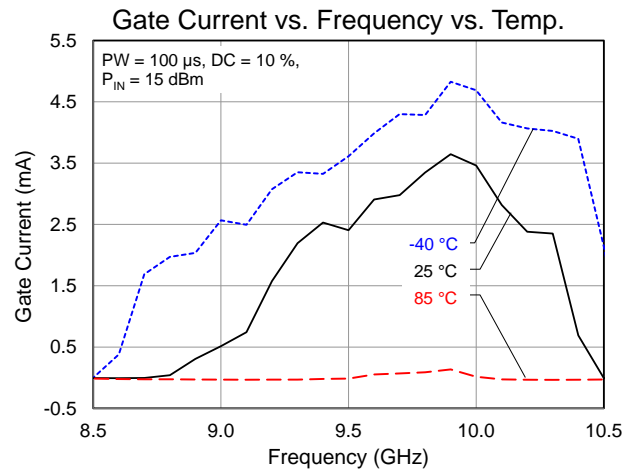
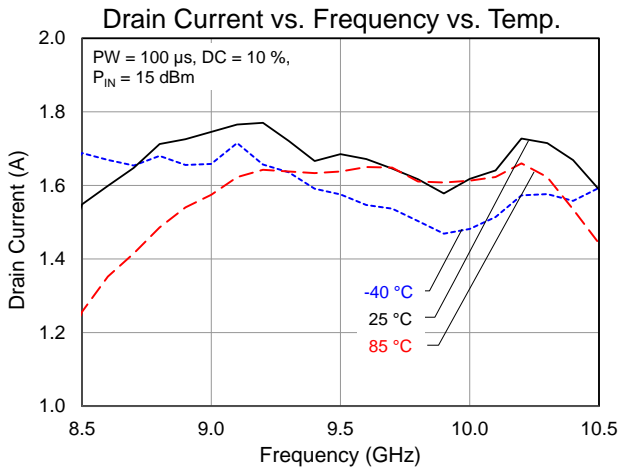
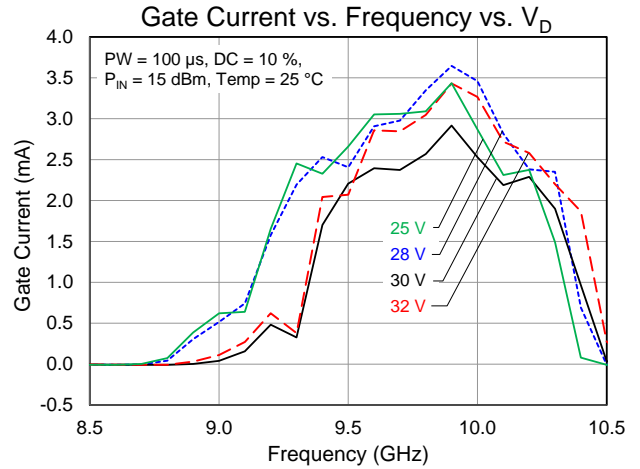
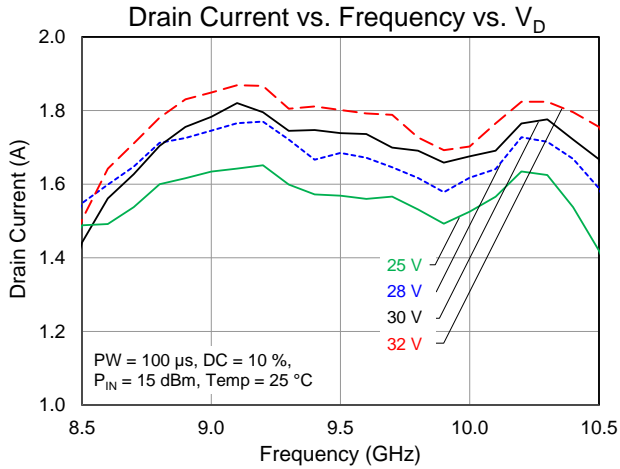
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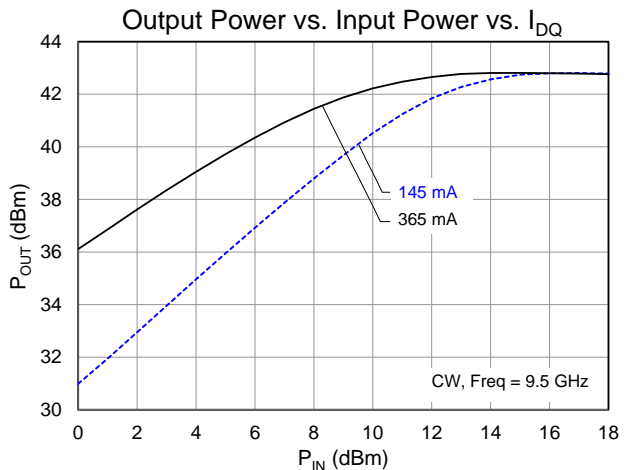
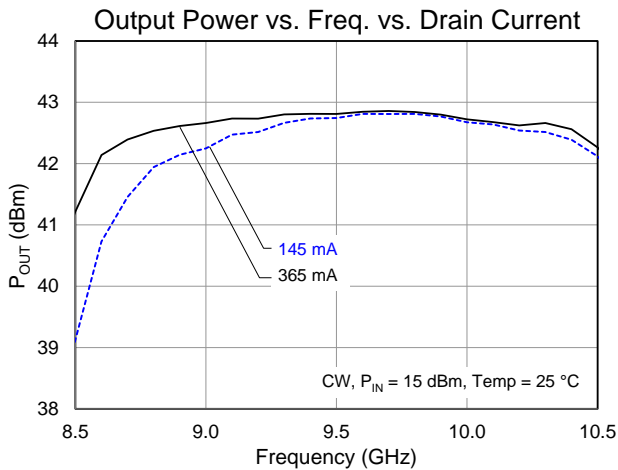
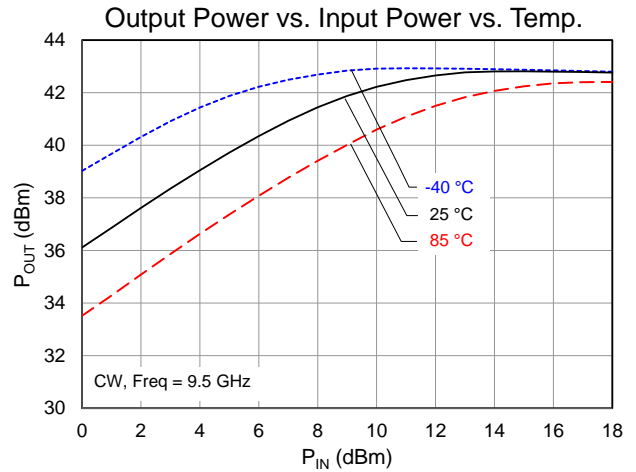
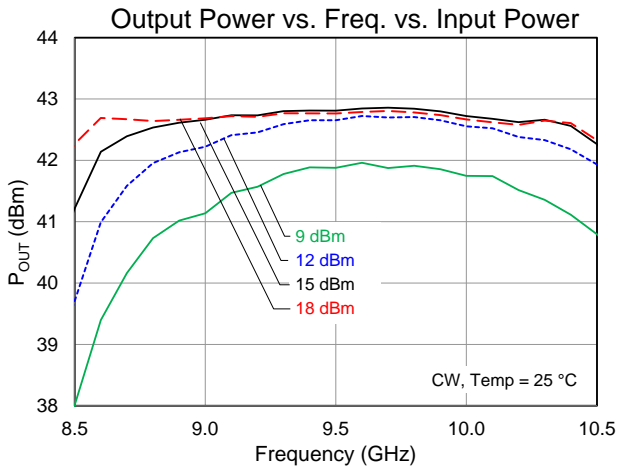
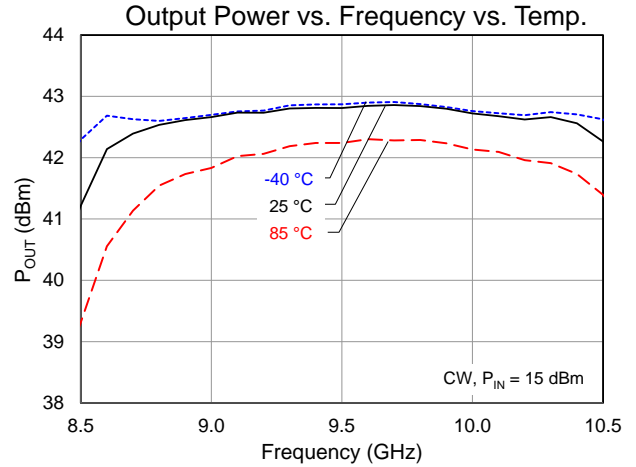
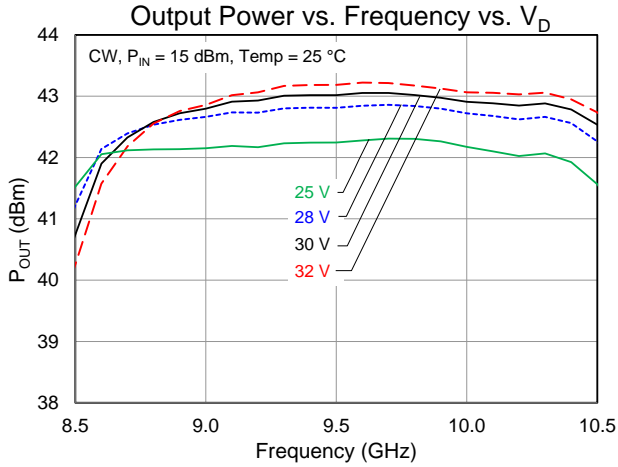
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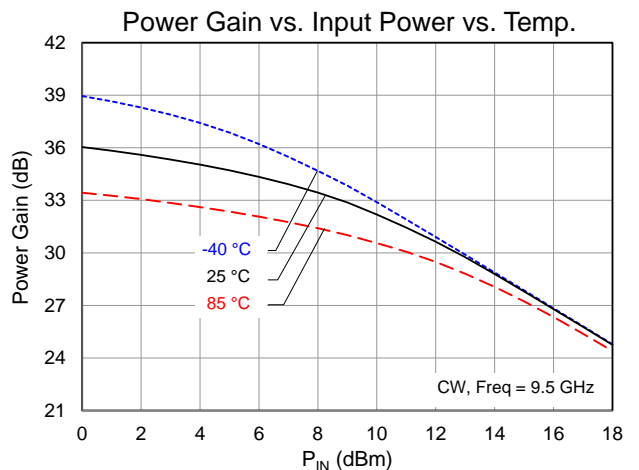
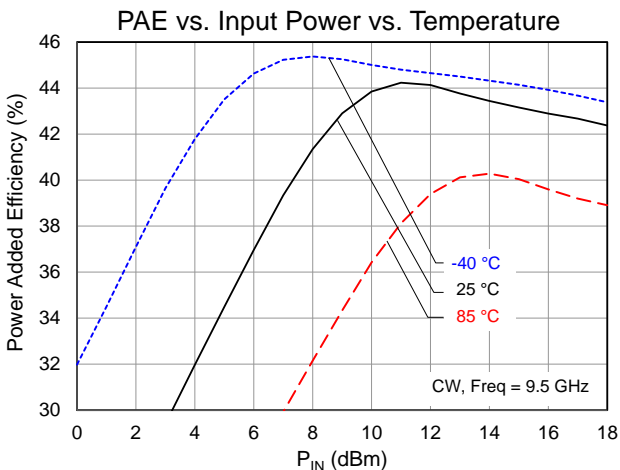
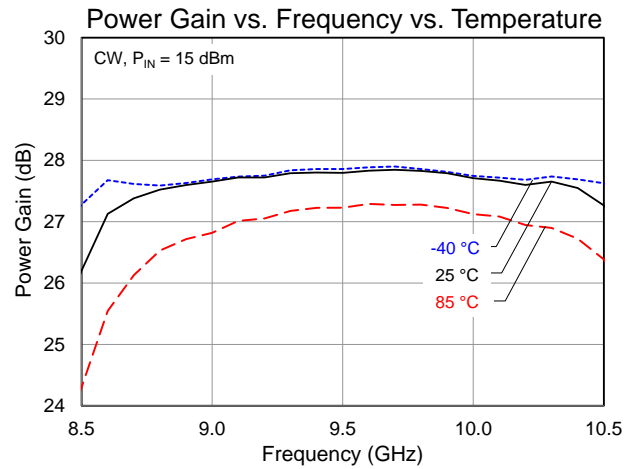
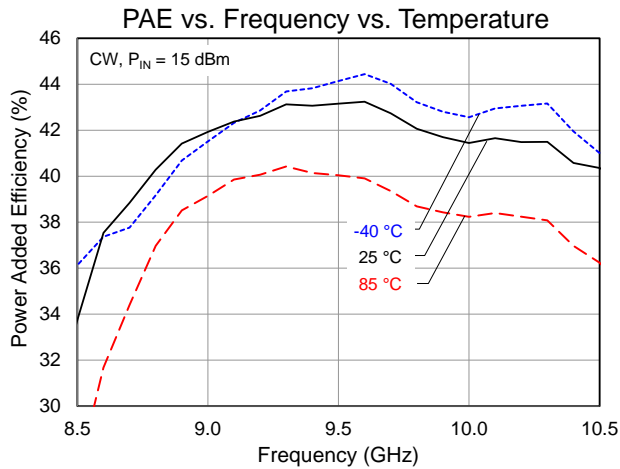
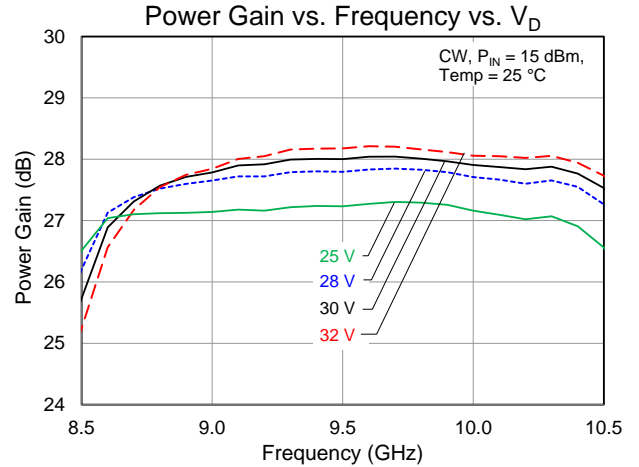
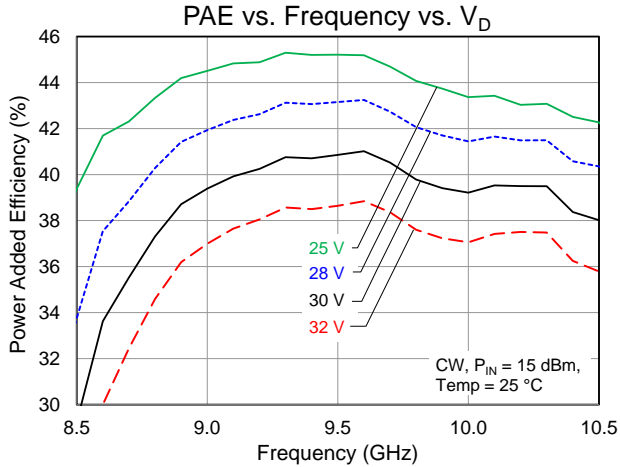
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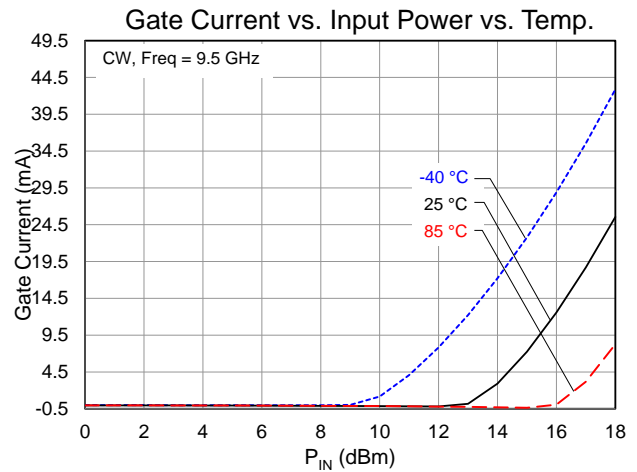
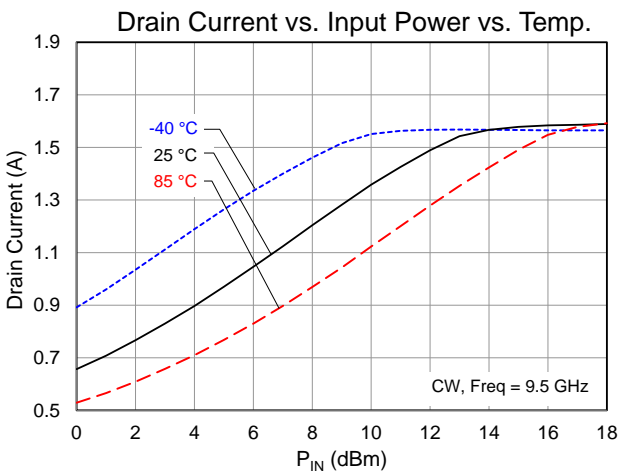
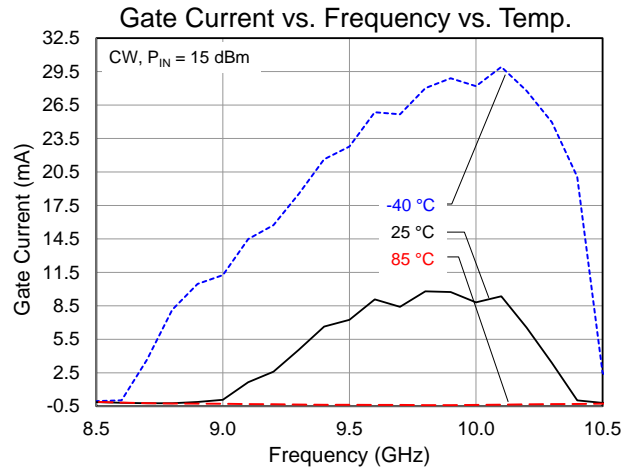
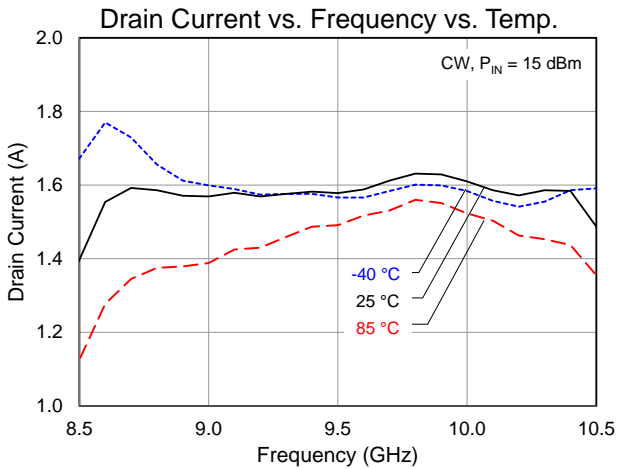
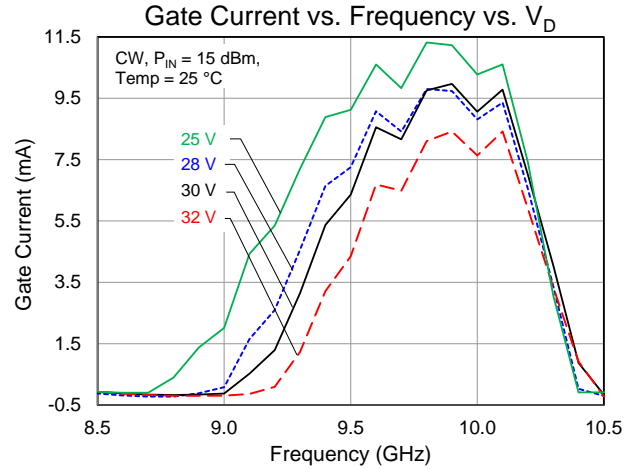
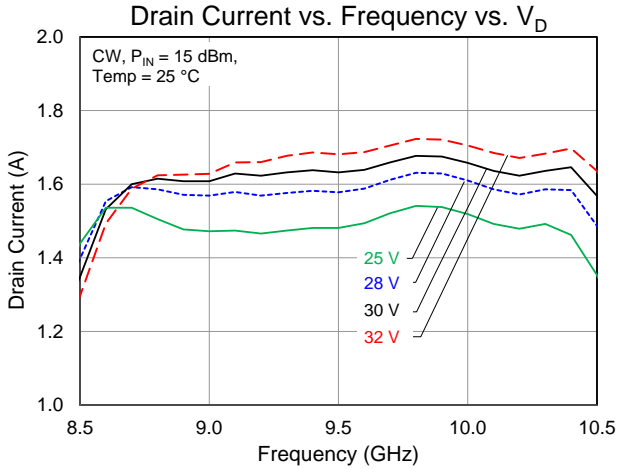
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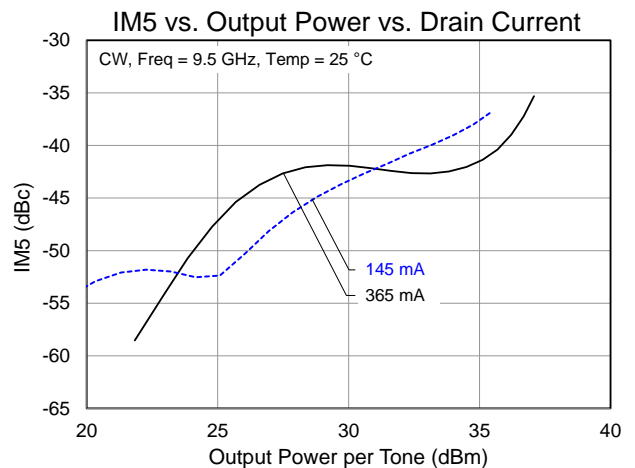
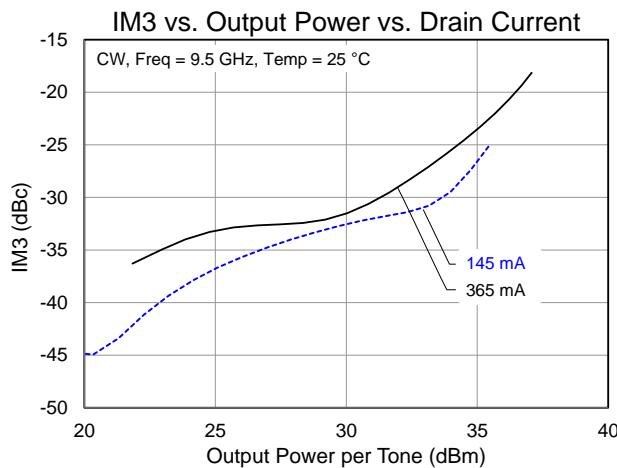
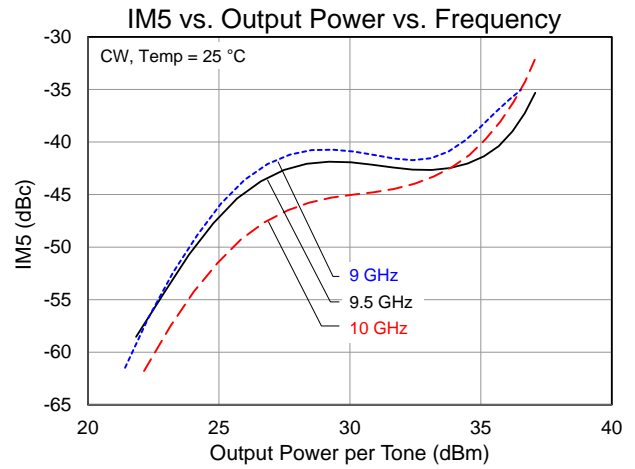
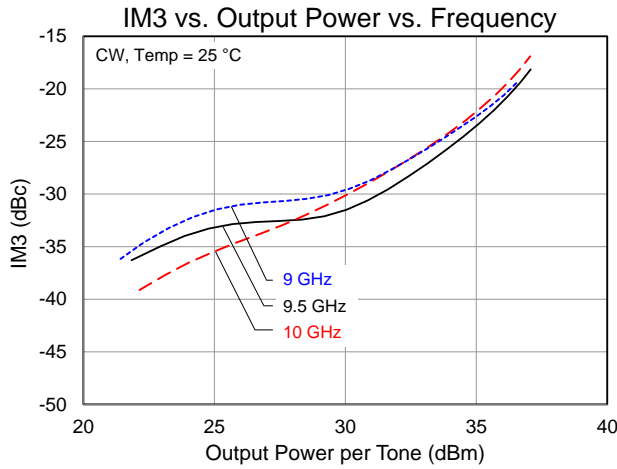
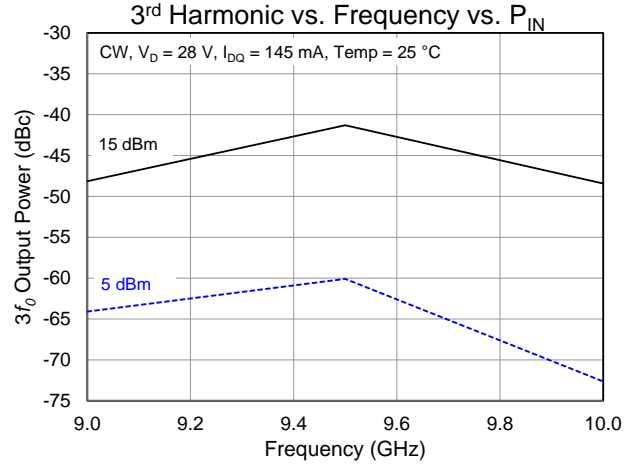
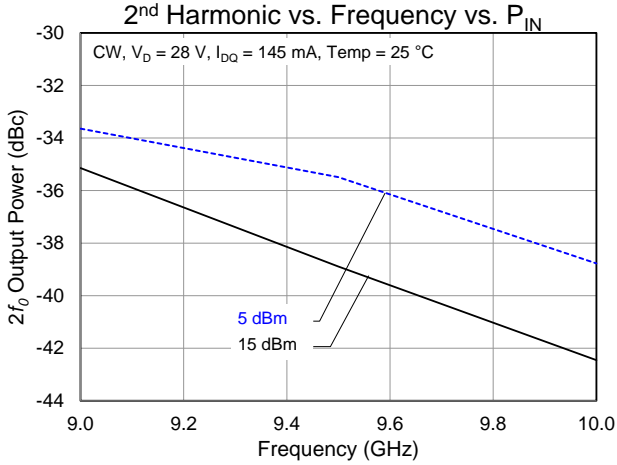
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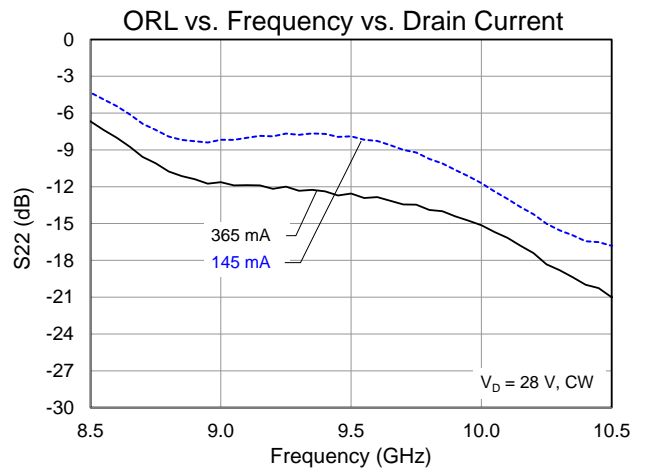
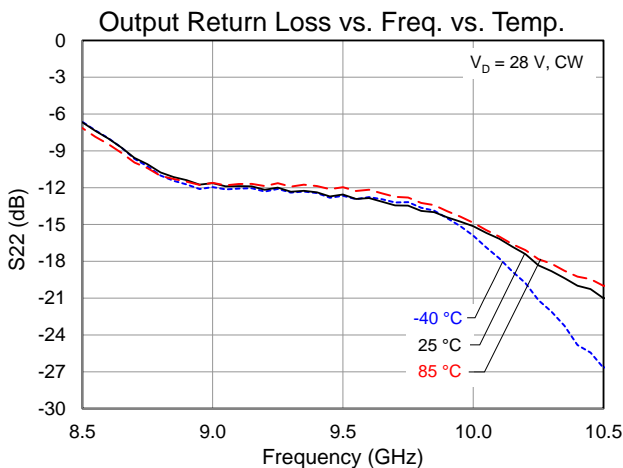
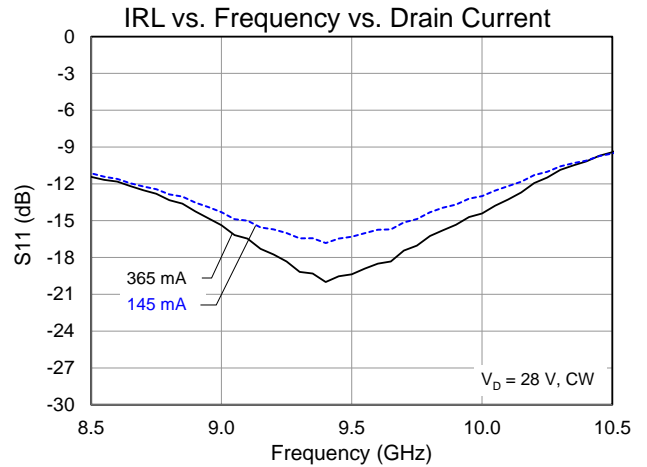
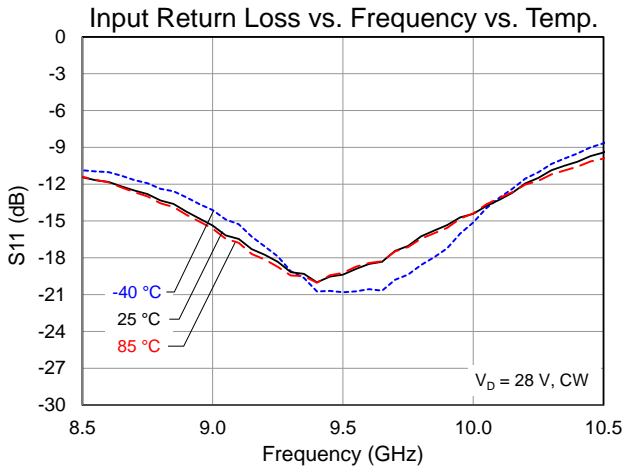
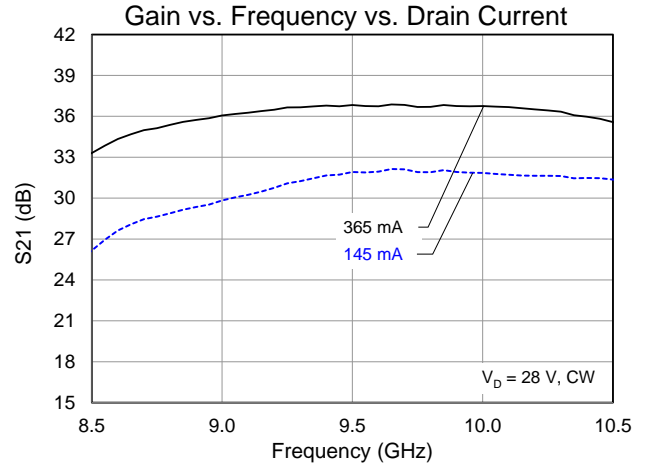
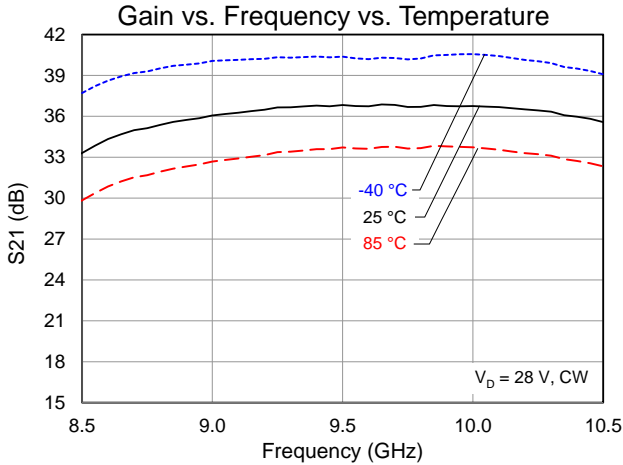
### Typical Performance: Linearity

Conditions unless otherwise specified:  $V_D = 28\text{ V}$ ,  $I_{DQ} = 365\text{ mA}$ ,  $V_G = -2.6\text{ V}$  typical.

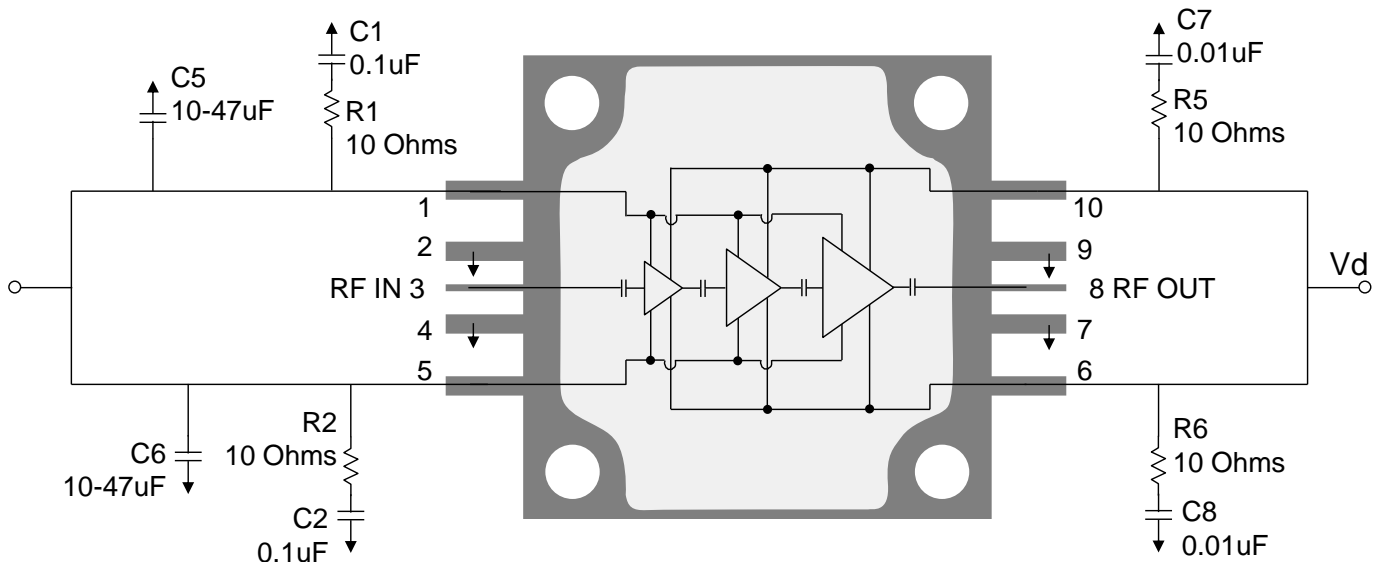


### Typical Performance: Small Signal

Conditions unless otherwise specified:  $V_D = 28\text{ V}$ ,  $I_{DQ} = 365\text{ mA}$ ,  $V_G = -2.6\text{ V}$  typical.



## Applications Information and Pin Layout



### Bias-up Procedure

1. Set  $I_D$  limit to 3 A,  $I_G$  limit to 14 mA
2. Apply  $-5$  V to  $V_G$
3. Apply  $+28$  V to  $V_D$ ; ensure  $I_{DQ}$  is approx. 0 mA
4. Adjust  $V_G$  until  $I_{DQ} = 365$  mA ( $V_G \sim -2.6$  V Typical).
5. Turn on RF supply

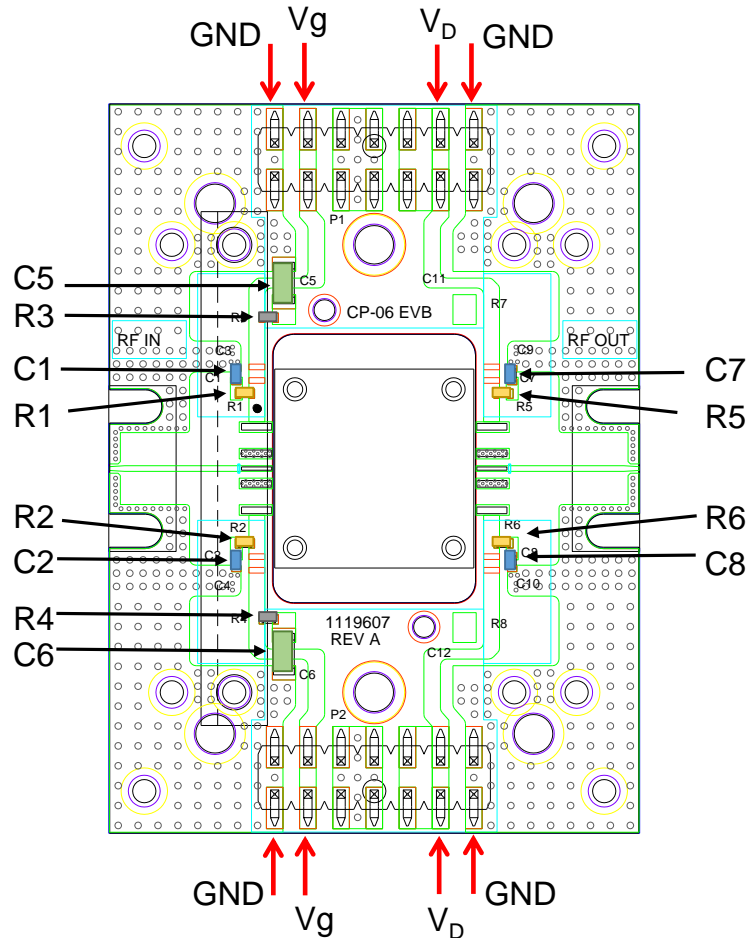
### Bias-down Procedure

1. Turn off RF supply
2. Reduce  $V_G$  to  $-5$  V; ensure  $I_{DQ}$  is approx. 0 mA
3. Set  $V_D$  to 0 V
4. Turn off  $V_D$  supply
5. Turn off  $V_G$  supply

### Pin Description

Pin No.	Symbol	Description
1,5	$V_G$	Gate Voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
3	$RF_{IN}$	Output; matched to 50 $\Omega$ ; DC blocked
2,4,7,9	GND	Must be grounded on the PCB.
6,10	$V_D$	Drain voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
8	$RF_{OUT}$	Input; matched to 50 $\Omega$ ; DC blocked

## Evaluation Board



NOTE: Both Top and Bottom Vd and Vg must be biased.

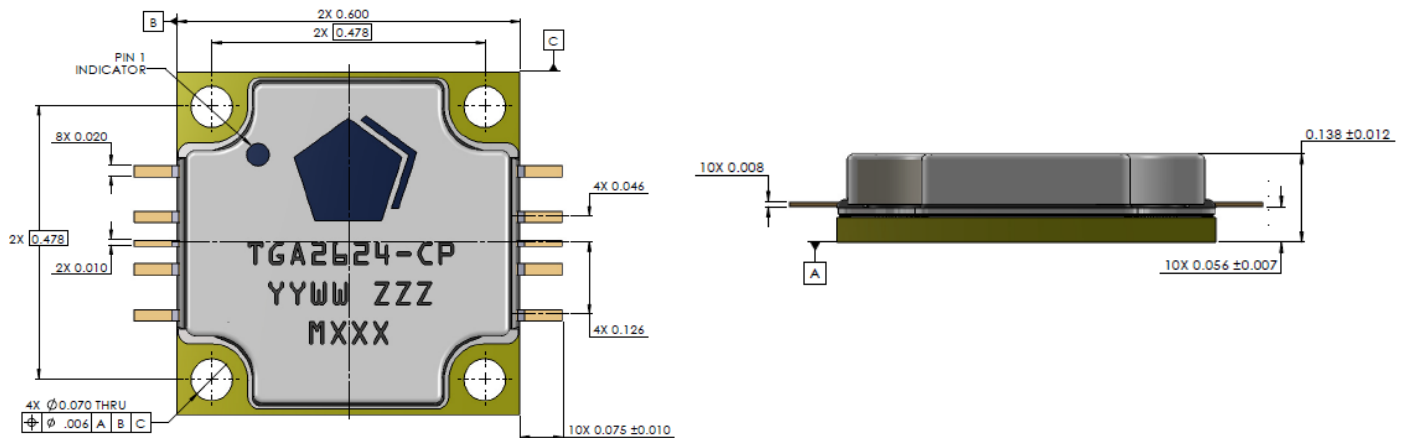
### Bill of Material

Reference Des.	Value	Description	Manuf.	Part Number
C1, C2	0.1 $\mu$ F	Cap, 0402, 50 V, 10%, X7R	Various	
C5, C6	10-47 $\mu$ F	Cap, 1206, 50 V, 20%, X5R (10v is OK)	Various	
C7, C8	0.01 $\mu$ F	Cap, 0402, 50V, 10%, X7R	Various	
R1, R2, R5, R6	10 Ohms	Res, 0402, 50V, 5%	Various	
R3, R4	0 Ohms	Res, 0402, jumper required for the above EVB design	Various	

**Assembly Notes**

1. Clean the board or module with alcohol. Allow it to dry fully.
2. Nylock screws are recommended for mounting the TGA2624-CP to the board.
3. To improve the thermal and RF performance, we recommend the following:
  - a. Apply thermal compound or 4 mils indium shim between the package and the board.
  - b. Attach a heat sink to the bottom of the board and apply thermal compound or 4 mils indium shim between the heat sink and the board.
4. Apply solder to each pin of the TGA2624-CP.
5. Clean the assembly with alcohol.

**Mechanical Information**



Units: inches

Tolerances: unless specified

x.xx = ± 0.01

x.xxx = ± 0.005

Materials:

Base: Copper

Lid: Plastic

All metalized features are gold plated

Part is epoxy sealed

Marking:

2624: Part number

YY: Part Assembly year

WW: Part Assembly week

ZZZ: Serial Number

MXXX: Batch ID

## Product Compliance Information

### ESD Sensitivity Ratings



Caution! ESD-Sensitive Device

ESD Rating: TBD  
Value: TBD  
Test: Human Body Model (HBM)  
Standard: JEDEC Standard JESD22-A114

### MSL Rating

Level 5A at 260 °C convection reflow.  
The part is rated Moisture Sensitivity Level 5A at 260 °C per JEDEC standard IPC/JEDEC J-STD-020.

### ECCN

US Department of Commerce: 3A001.b.2.b

### Solderability

Compatible with the latest version of J-STD-020, Lead-free solder, 260°C

### RoHS Compliance

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- PFOS Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

Web: [www.triquint.com](http://www.triquint.com)      Tel: +1.972.994.8465  
Email: [info-sales@triquint.com](mailto:info-sales@triquint.com)      Fax: +1.972.994.8504

For technical questions and application information:      Email: [info-products@triquint.com](mailto:info-products@triquint.com)

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